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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Active
Core Processor	PowerPC e500
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	800MHz
Co-Processors/DSP	-
RAM Controllers	DDR2, DDR3
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (2)
SATA	SATA 3Gbps (1)
USB	USB 2.0 (2)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 90°C (TA)
Security Features	-
Package / Case	783-BBGA, FCBGA
Supplier Device Package	783-FCPBGA (29x29)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mpc8535avjanga

1.1 Pin Map

See Table 1 for the MPC8535E pinout, which is a subset of the MPC8536E.

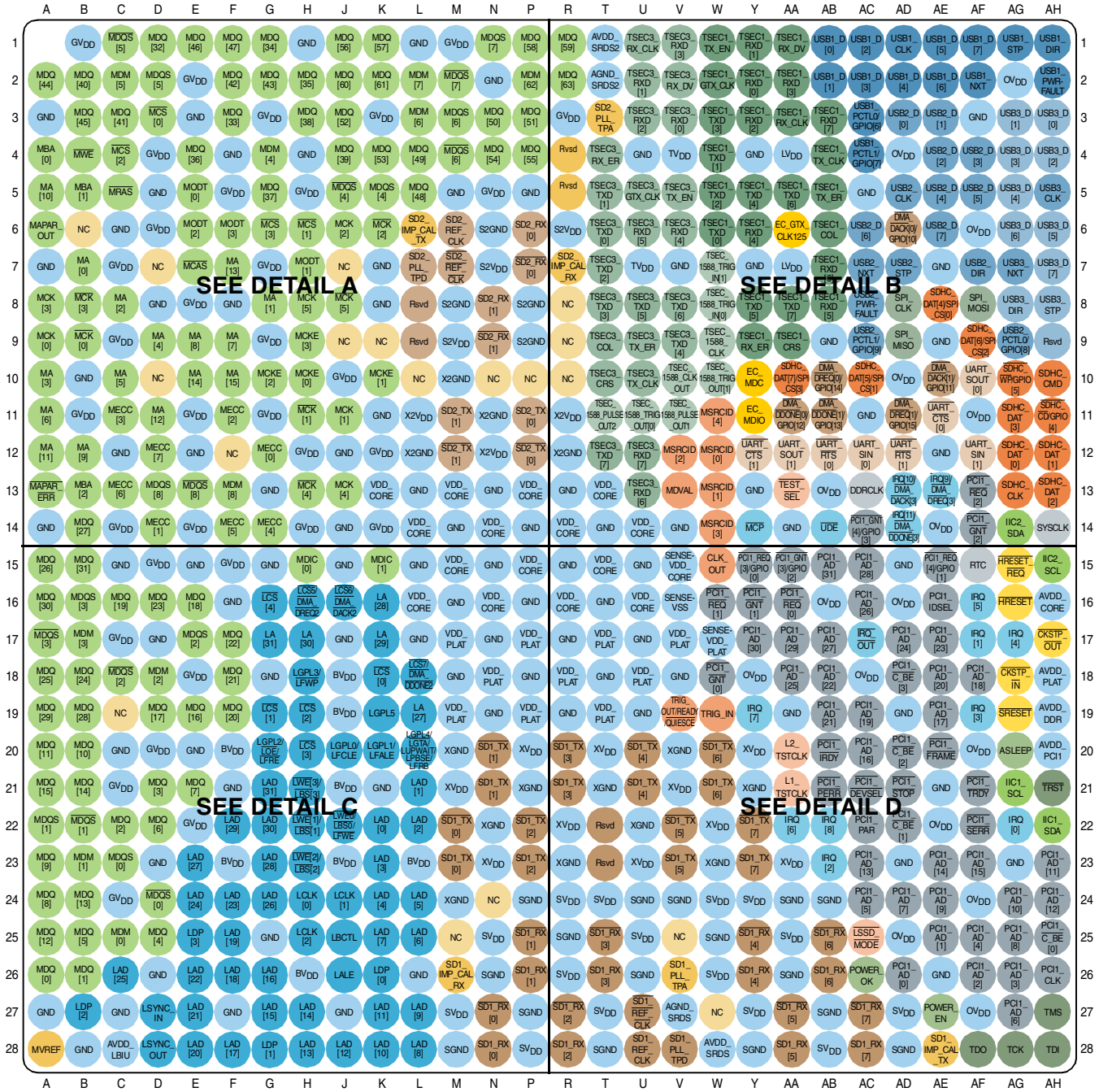


Figure 2. Chip Pin Map Bottom View

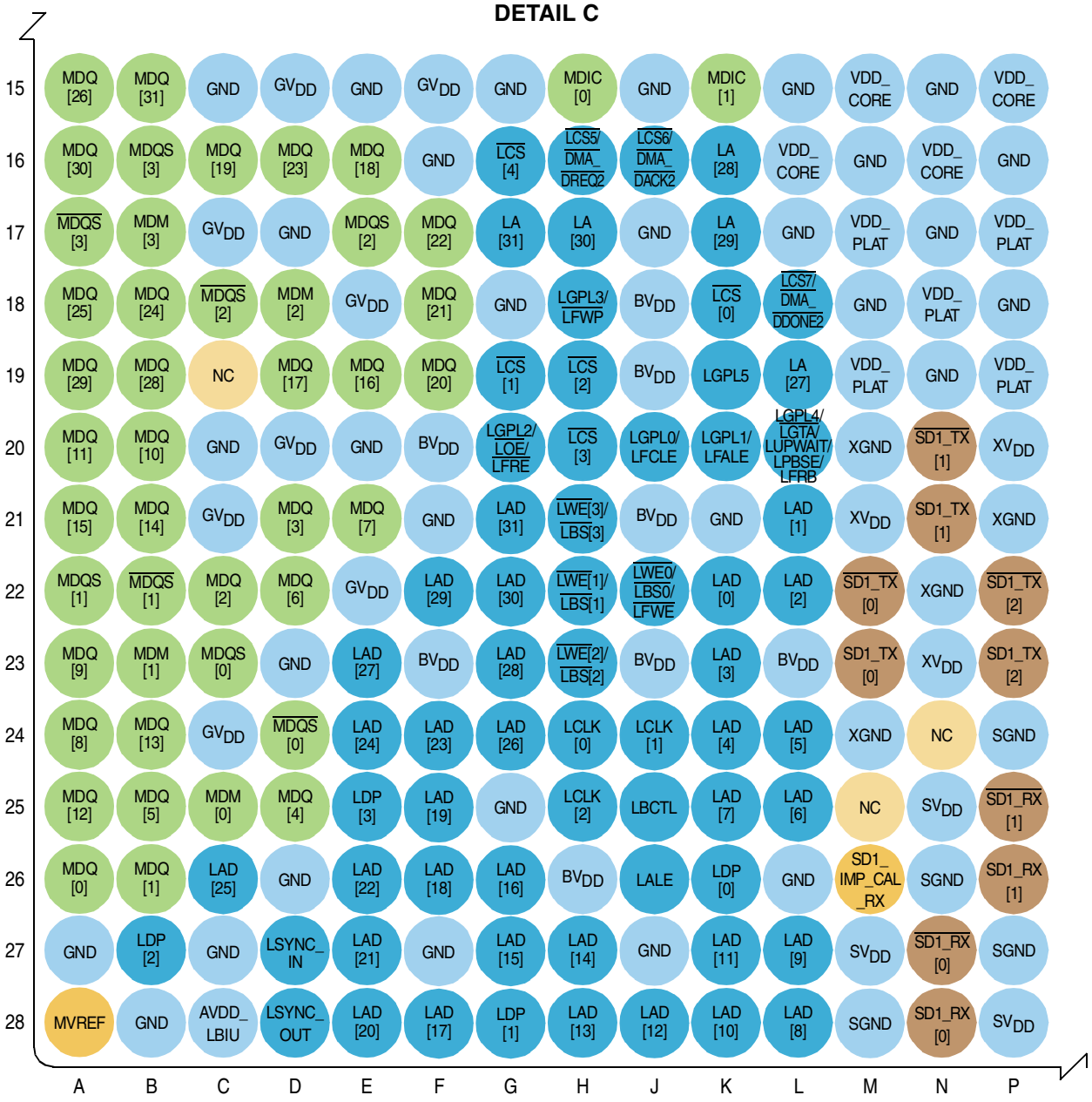


Figure 5. Chip Pin Map Detail C

Table 1. Pinout Listing (continued)

Signal	Signal Name	Package Pin Number	Pin Type	Power Supply	Notes
Programmable Interrupt Controller					
$\overline{\text{MCP}}$	Machine check processor	Y14	I	OV_{DD}	—
$\overline{\text{UDE}}$	Unconditional debug event	AB14	I	OV_{DD}	—
IRQ[0:8]	External interrupts	AG22,AF17,AB23, AF19,AG17,AF16, AA22,Y19,AB22	I	OV_{DD}	—
IRQ[9]/$\overline{\text{DMA\_DREQ[3]}}$	External interrupt/DMA request	AE13	I	OV_{DD}	1
IRQ[10]/$\overline{\text{DMA\_DACK[3]}}$	External interrupt/DMA Ack	AD13	I/O	OV_{DD}	1
IRQ[11]/$\overline{\text{DMA\_DDONE[3]}}$	External interrupt/DMA done	AD14	I/O	OV_{DD}	1
$\overline{\text{IRQ\_OUT}}$	Interrupt output	AC17	O	OV_{DD}	2,4
Ethernet Management Interface					
EC_MDC	Management data clock	Y10	O	OV_{DD}	5,9,22
EC_MDIO	Management data In/Out	Y11	I/O	OV_{DD}	—
Gigabit Reference Clock					
EC_GTX_CLK125	Reference clock	AA6	I	LV_{DD}	31
Three-Speed Ethernet Controller (Gigabit Ethernet 1)					
TSEC1_TXD[7:0]	Transmit data	AA8,AA5,Y8,Y5,W3, W5,W4,W6	O	LV_{DD}	5,9,22
TSEC1_TX_EN	Transmit Enable	W1	O	LV_{DD}	23
TSEC1_TX_ER	Transmit Error	AB5	O	LV_{DD}	5,9
TSEC1_TX_CLK	Transmit clock In	AB4	I	LV_{DD}	—
TSEC1_GTX_CLK	Transmit clock Out	W2	O	LV_{DD}	—
TSEC1_CRS	Carrier sense	AA9	I/O	LV_{DD}	17
TSEC1_COL	Collision detect	AB6	I	LV_{DD}	—
TSEC1_RXD[7:0]	Receive data	AB3,AB7,AB8,Y6,AA2, Y3,Y1,Y2	I	LV_{DD}	—
TSEC1_RX_DV	Receive data valid	AA1	I	LV_{DD}	—
TSEC1_RX_ER	Receive data error	Y9	I	LV_{DD}	—
TSEC1_RX_CLK	Receive clock	AA3	I	LV_{DD}	—
Three-Speed Ethernet Controller (Gigabit Ethernet 3)					
TSEC3_TXD[7:0]	Transmit data	T12,V8,U8,V9,T8,T7, T5,T6	O	TV_{DD}	5,9,22
TSEC3_TX_EN	Transmit Enable	V5	O	TV_{DD}	23
TSEC3_TX_ER	Transmit Error	U9	O	TV_{DD}	5,9

Table 1. Pinout Listing (continued)

Signal	Signal Name	Package Pin Number	Pin Type	Power Supply	Notes
XVDD	SerDes 1 transceiver supply	M21,N23,P20,R22,T20, U23,V21,W22,Y20, AA23	—	XV_{DD}	—
S2VDD	SerDes 2 core logic supply	R6,N7,M9	—	$S2V_{DD}$	—
X2VDD	SerDes 2 transceiver supply	R11,N12,L11	—	$X2V_{DD}$	—
VDD_CORE	Core, L2 logic supply	P13,U16,L16,M15,N14, R14,P15,N16,M13, U14,T13,L14,T15,R16, K13	—	V_{DD_CORE}	—
VDD_PLAT	Platform logic supply	T19,T17,V17,U18,R18, N18,M19,P19,P17,M17	—	V_{DD_PLAT}	—
AVDD_CORE	CPU PLL supply	AH16	—	AV_{DD_CORE}	20,28
AVDD_PLAT	Platform PLL supply	AH18	—	AV_{DD_PLAT}	20
AVDD_DDR	DDR PLL supply	AH19	—	AV_{DD_DDR}	20
AVDD_LBIU	Local Bus PLL supply	C28	—	AV_{DD_LBIU}	20
AVDD_PCI1	PCI PLL supply	AH20	—	AV_{DD_PCI1}	20
AVDD_SRDS	SerDes 1 PLL supply	W28	—	AV_{DD_SRDS}	20
AVDD_SRDS2	SerDes 2 PLL supply	T1	—	AV_{DD_SRDS2}	20
SENSEVDD_CORE	—	V15	—	V_{DD_CORE}	13
SENSEVDD_PLAT	—	W17	—	V_{DD_PLAT}	13
GND	Ground	D5,AE7,F4,D26,D23, C12,C15,E20,D8,B10, AF3,E3,J14,K21,F8,A3, F16,E12,E15,D17,L1, F21,H1,G13,G15,G18, C6,A14,A7,G25,H4, C20,J12,J15,J17,F27, M5,J27,K11,L26,K7, K8,T14,V14,M16,M18, P14,N15,N17,N19,N2, P5,P16,P18,M14,R15, R17,R19,T16,T18,L17, U15,U17,U19,V18,C27, Y13,AE26,AA19,AE21, B28,AC11,AD19,AD23, L15,AD15,AG23,AE9, A27,V7,Y7,AC5,U4,Y4, AE12,AB9,AA14,N13, R13,L13	—	—	—
XGND	SerDes 1Transceiver pad GND (xpadvss)	M20,M24,N22,P21, R23,T21,U22,V20, W23, Y21	—	—	—

Table 3. Recommended Operating Conditions

Characteristic		Symbol	Recommended Value	Unit	Notes
Core supply voltage		V_{DD_CORE}	1.0 ± 50 mV	V	—
Platform supply voltage		V_{DD_PLAT}	1.0 ± 50 mV	V	—
PLL core supply voltage		AV_{DD_CORE}	1.0 ± 50 mV	V	2
PLL other supply voltage		AV_{DD}	1.0 ± 50 mV	V	2
Core power supply for SerDes transceivers		SV_{DD}	1.0 ± 50 mV	V	—
Pad power supply for SerDes transceivers and PCI Express		XV_{DD}	1.0 ± 50 mV	V	—
DDR SDRAM Controller I/O supply voltage	DDR2 SDRAM Interface	GV_{DD}	1.8 V ± 90 mV	V	3
	DDR3 SDRAM Interface		1.5 V ± 75 mV		
Three-speed Ethernet I/O voltage		LV_{DD} (eTSEC1)	3.3 V ± 165 mV 2.5 V ± 125 mV	V	5
		TV_{DD} (eTSEC3)	3.3 V ± 165 mV 2.5 V ± 125 mV		
PCI, DUART, system control and power management, I^2C, USB, eSDHC, eSPI and JTAG I/O voltage, MII management voltage		OV_{DD}	3.3 V ± 165 mV	V	4
Local bus I/O voltage		BV_{DD}	3.3 V ± 165 mV 2.5 V ± 125 mV 1.8 V ± 90 mV	V	—
Input voltage	DDR2 and DDR3 SDRAM Interface signals	MV_{IN}	GND to GV_{DD}	V	3
	DDR2 and DDR3 SDRAM Interface reference	MV_{REF}	$GV_{DD}/2$ ± 1%	V	—
	Three-speed Ethernet signals	LV_{IN} TV_{IN}	GND to LV_{DD} GND to TV_{DD}	V	5
	Local bus signals	BV_{IN}	GND to BV_{DD}	V	—
	PCI, Local bus, DUART, SYSCLK, system control and power management, I^2C, and JTAG signals	OV_{IN}	GND to OV_{DD}	V	4
Operating Temperature range	Commercial	T_A T_J	T_A= 0 (min) to T_J= 90(max)	°C	6
	Industrial standard temperature range		T_A= 0 (min) to T_J= 105 (max)		
	Extended temperature range		T_A= -40 (min) to T_J= 105 (max)		

Notes:

2. This voltage is the input to the filter discussed in Section 3.2.1, "PLL Power Supply Filtering," and not necessarily the voltage at the AVDD pin, which may be reduced from VDD by the filter.
3. **Caution**: MVIN must not exceed GVDD by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
4. **Caution**: OVIN must not exceed OVDD by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
5. **Caution**: L/TVIN must not exceed L/TVDD by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
6. Minimum temperature is specified with T_A; maximum temperature is specified with T_J.

2.3 Power Characteristics

The estimated power dissipation for the core complex bus (CCB) versus the core frequency for this family of PowerQUICC III chips is shown in the following table.

Table 5. Power Dissipation [5]

Power Mode	Core Frequency	CCB Frequency	DDR Frequency	V_{DD} Platform	V_{DD} Core	Junction Temperature	Core Power		Platform Power[9]		Notes
	(MHz)	(MHz)	(MHz)	(V)	(V)	(°C)	mean[7]	Max	mean[7]	Max	
Maximum (A)	600	400	400	1.0	1.0	105 /90	—	4.1/3.3	—	4.7/3.7	1, 3, 8
Thermal (W)							—	3.7/2.9	—	4.7/3.7	1, 4, 8
Typical (W)						65	1.5	—	1.5	—	1, 2
Doze (W)							1.2	1.9	1.4	1.9	1
Nap (W)							0.8	1.5	1.4	1.9	1
Sleep (W)							0.8	1.5	1.0	1.6	1
Deep Sleep (W)						35	0	0	0.6	1.1	6
Maximum (A)	800	400	400	1.0	1.0	105 / 90	—	4.5/3.7	—	4.7/3.7	1, 3, 8
Thermal (W)							—	3.9/3.1	—	4.7/3.7	1, 4, 8
Typical (W)						65	1.7	—	1.5	—	1, 2
Doze (W)							1.3	2.1	1.4	1.9	1
Nap (W)							0.8	1.5	1.4	1.9	1
Sleep (W)							0.8	1.5	1.0	1.6	1
Deep Sleep (W)						35	0	0	0.6	1.1	1,6
Maximum (A)	1000	400	400	1.0	1.0	105 / 90	—	4.8/4.0	—	4.7/3.7	1, 3, 8
Thermal (W)							—	4.1/3.3	—	4.7/3.7	1, 4, 8
Typical (W)						65	1.9	—	1.5	—	1, 2
Doze (W)							1.4	2.2	1.4	1.9	1
Nap (W)							0.8	1.6	1.4	1.9	1
Sleep (W)							0.8	1.6	1.0	1.6	1
Deep Sleep (W)						35	0	0	0.6	1.1	1, 6

2.4 Input Clocks

2.4.1 System Clock Timing

This table provides the system clock (SYSCLK) AC timing specifications for the chip.

Table 6. SYSCLK AC Timing Specifications

At recommended operating conditions (see Table 2) with OV_{DD} = 3.3 V ± 165 mV.

Parameter/Condition	Symbol	Min	Typical	Max	Unit	Notes
SYSCLK frequency	f_{SYSCLK}	33	—	133	MHz	1
SYSCLK cycle time	t_{SYSCLK}	7.5	—	30	ns	—
SYSCLK rise and fall time	t_{KH}, t_{KL}	0.6	1.0	2.1	ns	2
SYSCLK duty cycle	t_{KHK}/t_{SYSCLK}	40	—	60	%	—
SYSCLK jitter	—	—	—	+/-150	ps	3, 4

Notes:
1. **Caution:** The CCB clock to SYSCLK ratio and e500 core to CCB clock ratio settings must be chosen such that the resulting SYSCLK frequency, e500 (core) frequency, and CCB clock frequency do not exceed their respective maximum or minimum operating frequencies. See Section 2.23.2, "CCB/SYSCLK PLL Ratio," and Section 2.23.3, "e500 Core PLL Ratio," for ratio settings.
2. Rise and fall times for SYSCLK are measured at 0.6 V and 2.7 V.
3. The SYSCLK driver's closed loop jitter bandwidth should be <500 kHz at -20 dB. The bandwidth must be set low to allow cascade-connected PLL-based devices to track SYSCLK drivers with the specified jitter.
4. For spread spectrum clocking, guidelines are +0% to -1% down spread at a modulation rate between 20 KHz and 60 KHz on SYSCLK.

2.4.2 PCI Clock Timing

When the PCI controller is configured for asynchronous operation, the reference clock for the PCI controller is not the SYSCLK input, but instead the PCI_CLK. This table provides the PCI reference clock AC timing specifications for the chip.

Table 7. PCICLK AC Timing Specifications

At recommended operating conditions (see Table 2) with OV_{DD} = 3.3 V ± 165 mV.

Parameter/Condition	Symbol	Min	Typical	Max	Unit	Notes
PCICLK frequency	f_{PCICLK}	33	—	66	MHz	—
PCICLK cycle time	t_{PCICLK}	15	—	30	ns	—
PCICLK rise and fall time	t_{KH}, t_{KL}	0.6	1.0	2.1	ns	1
PCICLK duty cycle	t_{KHK}/t_{PCICLK}	40	—	60	%	—

Notes:
1. Rise and fall times for PCICLK are measured at 0.6 V and 2.7 V.

2.4.3 Real Time Clock Timing

The RTC input is sampled by the platform clock (CCB clock). The output of the sampling latch is then used as an input to the counters of the PIC and the TimeBase unit of the e500. There is no jitter specification. The minimum pulse width of the RTC signal should be greater than 2x the period of the CCB clock. That is, minimum clock high time is $2 \times t_{CCB}$, and minimum clock low time is $2 \times t_{CCB}$. There is no minimum RTC frequency; RTC may be grounded if not needed.

2.4.4 eTSEC Gigabit Reference Clock Timing

This table provides the eTSEC gigabit reference clocks (EC_GTX_CLK125) AC timing specifications for the chip.

Table 8. EC_GTX_CLK125 AC Timing Specifications

Parameter/Condition	Symbol	Min	Typical	Max	Unit	Notes
EC_GTX_CLK125 frequency	f_{G125}	—	125	—	MHz	—
EC_GTX_CLK125 cycle time	t_{G125}	—	8	—	ns	—
EC_GTX_CLK rise and fall time LV_{DD}, TV_{DD} = 2.5V LV_{DD}, TV_{DD} = 3.3V	t_{G125R}/t_{G125F}	—	—	 0.75 1.0	ns	1
EC_GTX_CLK125 duty cycle GMII, TBI 1000Base-T for RGMII, RTBI	t_{G125H}/t_{G125}	 45 47	—	 55 53	%	2

Notes:

1. Rise and fall times for EC_GTX_CLK125 are measured from 0.5V and 2.0V for L/TVDD=2.5V, and from 0.6 and 2.7V for L/TVDD=3.3V at 0.6 V and 2.7 V.
2. EC_GTX_CLK125 is used to generate the GTX clock for the eTSEC transmitter with 2% degradation. EC_GTX_CLK125 duty cycle can be loosened from 47/53% as long as the PHY device can tolerate the duty cycle generated by the eTSEC GTX_CLK. See Section 2.9.2.6, "RGMII and RTBI AC Timing Specifications," for duty cycle for 10Base-T and 100Base-T reference clock.

2.4.5 DDR Clock Timing

This table provides the DDR clock (DDRCLK) AC timing specifications for the chip.

Table 9. DDRCLK AC Timing Specifications

At recommended operating conditions with OV_{DD} of 3.3V ± 5%.

Parameter/Condition	Symbol	Min	Typical	Max	Unit	Notes
DDRCLK frequency	f_{DDRCLK}	66	—	166	MHz	1
DDRCLK cycle time	t_{DDRCLK}	6.0	—	15.15	ns	—
DDRCLK rise and fall time	t_{KH}, t_{KL}	0.6	1.0	1.2	ns	2
DDRCLK duty cycle	t_{KHK}/t_{DDRCLK}	40	—	60	%	—
DDRCLK jitter	—	—	—	+/– 150	ps	3, 4

Notes:

1. **Caution:** The DDR complex clock to DDRCLK ratio settings must be chosen such that the resulting DDR complex clock frequency does not exceed the maximum or minimum operating frequencies. See Section 2.23.4, "DDR/DDRCLK PLL Ratio," for ratio settings.
2. Rise and fall times for DDRCLK are measured at 0.6 V and 2.7 V.
3. The DDRCLK driver's closed loop jitter bandwidth should be <500 kHz at –20 dB. The bandwidth must be set low to allow cascade-connected PLL-based devices to track DDRCLK drivers with the specified jitter.
4. For spread spectrum clocking, guidelines are +0% to –1% down spread at a modulation rate between 20 kHz and 60 kHz on DDRCLK.

Table 21. SPI AC Timing Specifications[1] (continued)

Characteristic	Symbol [2]	Min	Max	Unit	Note
SPI_CS outputs—Master data delay	$t_{NIKHOV2}$	—	6.0	ns	—
SPI inputs—Master data input setup time	t_{NIIVKH}	5	—	ns	—
SPI inputs—Master data input hold time	t_{NIIXKH}	0	—	ns	—

Notes:

1. Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.
2. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{NIKHOV} symbolizes the NMSI outputs internal timing (NI) for the time t_{SPI} memory clock reference (K) goes from the high state (H) until outputs (O) are valid (V).
3. SPCOM[RxDelay] is set to 0.
4. SPCOM[RxDelay] is set to 1.

This figure provides the AC test load for the SPI.

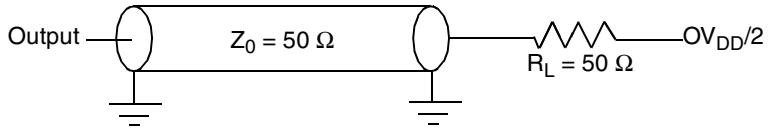
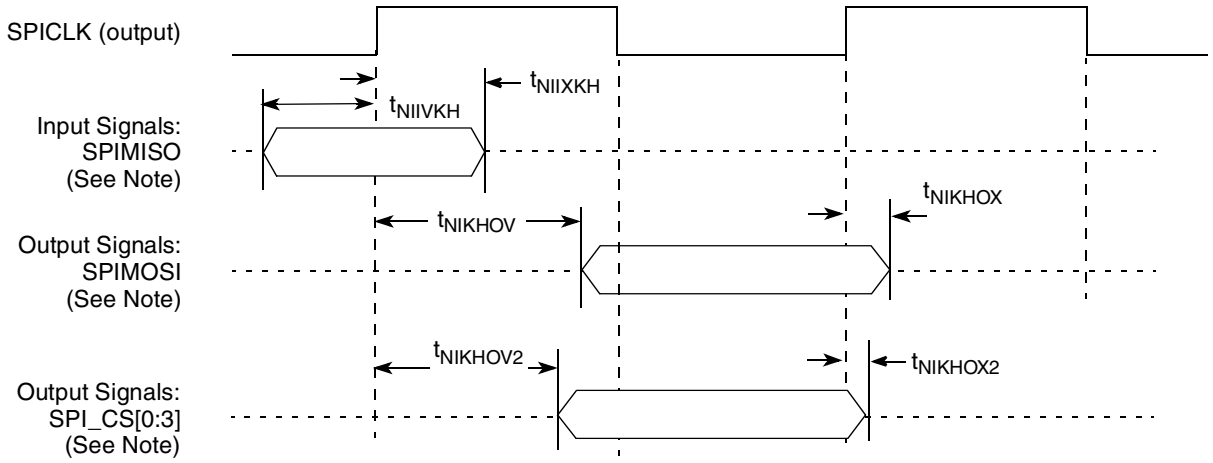


Figure 12. SPI AC Test Load

This figure represents the AC timing from Table 21. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.



Note: The clock edge is selectable on SPI.

Figure 13. SPI AC Timing in Master mode (Internal Clock) Diagram

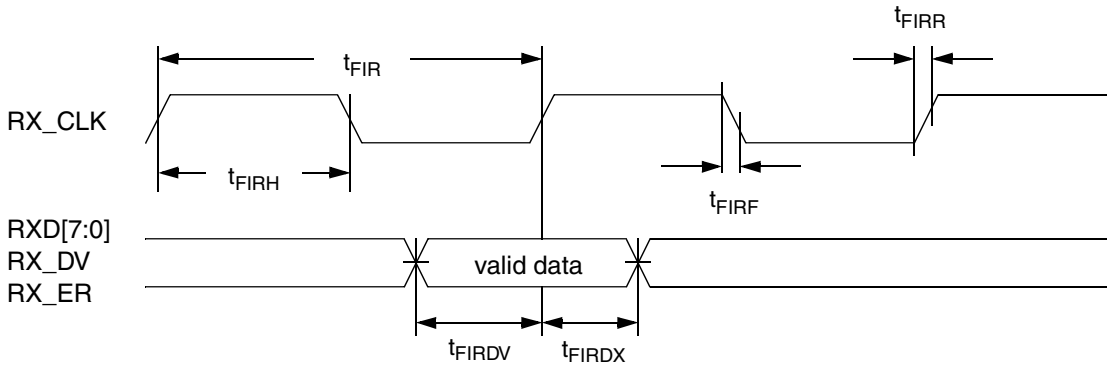


Figure 15. FIFO Receive AC Timing Diagram

2.9.2.2 GMII AC Timing Specifications

This section describes the GMII transmit and receive AC timing specifications.

2.9.2.2.1 GMII Transmit AC Timing Specifications

This table provides the GMII transmit AC timing specifications.

Table 28. GMII Transmit AC Timing Specifications

At recommended operating conditions with L/TV_{DD} of 3.3 V ± 5%.

Parameter/Condition	Symbol [1]	Min	Typ	Max	Unit
GTX_CLK clock period	t_{GTK}	—	8.0	—	ns
GTX_CLK to GMII data TXD[7:0], TX_ER, TX_EN delay	t_{GTKHDX}[3]	0.5	—	5.0	ns
GTX_CLK data clock rise time (20%-80%)	t_{GTXR}	—	—	1.0	ns
GTX_CLK data clock fall time (80%-20%)	t_{GTXF}	—	—	1.0	ns

Notes:

1. The symbols used for timing specifications herein follow the pattern $t_{\text{(first two letters of functional block)(signal)(state) (reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{GTKHDV} symbolizes GMII transmit timing (GT) with respect to the t_{GTX} clock reference (K) going to the high state (H) relative to the time date input signals (D) reaching the valid state (V) to state or setup time. Also, t_{GTKHDX} symbolizes GMII transmit timing (GT) with respect to the t_{GTX} clock reference (K) going to the high state (H) relative to the time date input signals (D) going invalid (X) or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{GTX} represents the GMII(G) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
2. Data valid t_{GTKHDV} to GTX_CLK Min Setup time is a function of clock period and max hold time. (Min Setup = Cycle time - Max Hold)

This figure shows the GMII receive AC timing diagram.

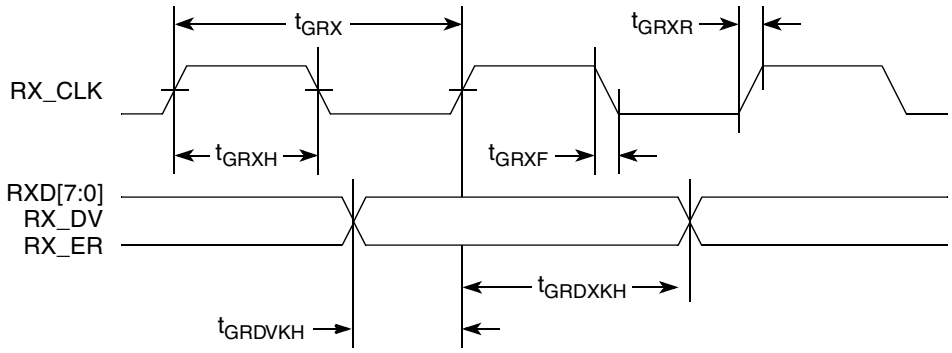


Figure 18. GMII Receive AC Timing Diagram

2.9.2.3 MII AC Timing Specifications

This section describes the MII transmit and receive AC timing specifications.

2.9.2.3.1 MII Transmit AC Timing Specifications

This table provides the MII transmit AC timing specifications.

Table 30. MII Transmit AC Timing Specifications

At recommended operating conditions with L/TV_{DD} of 3.3 V ± 5%.

Parameter/Condition	Symbol [1]	Min	Typ	Max	Unit
TX_CLK clock period 10 Mbps	t_{MTX}	—	400	—	ns
TX_CLK clock period 100 Mbps	t_{MTX}	—	40	—	ns
TX_CLK duty cycle	t_{MTXH}/t_{MTX}	35	—	65	%
TX_CLK to MII data TXD[3:0], TX_ER, TX_EN delay	t_{MTKHDX}	1	5	15	ns
TX_CLK data clock rise (20%-80%)	t_{MTXR}	1.0	—	4.0	ns
TX_CLK data clock fall (80%-20%)	t_{MTXF}	1.0	—	4.0	ns

Note:

1. The symbols used for timing specifications herein follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state) (reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{MTKHDX} symbolizes MII transmit timing (MT) for the time t_{MTX} clock reference (K) going high (H) until data outputs (D) are invalid (X). Note that, in general, the clock reference symbol representation is based on two to three letters representing the clock of a particular functional. For example, the subscript of t_{MTX} represents the MII(M) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

2.9.3.3 SGMII Transmitter and Receiver DC Electrical Characteristics

The following tables describe the SGMII SerDes transmitter and receiver AC-Coupled DC electrical characteristics. Transmitter DC characteristics are measured at the transmitter outputs (SD2_TX[n] and $\overline{\text{SD2\_TX}}$[n]) as depicted in Figure 30.

Table 39. SGMII DC Transmitter Electrical Characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Notes
Supply Voltage	$X2V_{DD}$	0.95	1.0	1.05	V	—
Output high voltage	VOH	—	—	$X2V_{DD\text{-}Typ}/2 + \lvert V_{OD}\rvert_{-max}/2$	mV	1
Output low voltage	VOL	$X2V_{DD\text{-}Typ}/2 - \lvert V_{OD}\rvert_{-max}/2$	—	—	mV	1
Output ringing	V_{RING}	—	—	10	%	—
Output differential voltage[2, 3, 5]	$\lvert V_{OD}\rvert$	323	500	725	mV	Equalization setting: 1.0x
		296	459	665		Equalization setting: 1.09x
		269	417	604		Equalization setting: 1.2x
		243	376	545		Equalization setting: 1.33x
		215	333	483		Equalization setting: 1.5x
		189	292	424		Equalization setting: 1.71x
		162	250	362		Equalization setting: 2.0x
Output offset voltage	V_{OS}	425	500	575	mV	1, 4
Output impedance (single-ended)	R_O	40	—	60	Ω	—
Mismatch in a pair	ΔR_O	—	—	10	%	—
Change in V_{OD} between “0” and “1”	$\Delta \lvert V_{OD}\rvert$	—	—	25	mV	—
Change in V_{OS} between “0” and “1”	ΔV_{OS}	—	—	25	mV	—
Output current on short to GND	I_{SA}, I_{SB}	—	—	40	mA	—

Notes:

1. This will not align to DC-coupled SGMII. $X2V_{DD\text{-}Typ}$=1.0V.
2. $\lvert V_{OD}\rvert = \lvert V_{SD2\_TXn} - V_{\overline{SD2\_TXn}}\rvert$. $\lvert V_{OD}\rvert$ is also referred as output differential peak voltage. $V_{TX\text{-}DIFFp\text{-}p} = 2*\lvert V_{OD}\rvert$.
3. The $\lvert V_{OD}\rvert$ value shown in the table assumes the following transmit equalization setting in the XMITEQ**AB** (for SerDes 2 lanes A & B) or XMITEQ**EF** (for SerDes 2 lanes E & E) bit field of the chip’s SerDes 2 control register:
   - The MSbit (bit 0) of the above bit field is set to zero (selecting the full $V_{DD\text{-}DIFF\text{-}p\text{-}p}$ amplitude - power up default);
   - The LSbits (bit [1:3]) of the above bit field is set based on the equalization setting shown in table.
4. V_{OS} is also referred to as output common mode voltage.
   - 5.The $\lvert V_{OD}\rvert$ value shown in the Typ column is based on the condition of $X2V_{DD\text{-}Typ}$=1.0V, no common mode offset variation (VOS =550mV), SerDes2 transmitter is terminated with 100-Ω differential load between SD2_TX[n] and SD2_TX[n].

Table 40. SGMII DC Receiver Electrical Characteristics (continued)

Parameter	Symbol	Min	Typ	Max	Unit	Notes
Receiver differential input impedance	Z_{RX_DIFF}	80	100	120	Ω	—
Receiver common mode input impedance	Z_{RX_CM}	20	—	35	Ω	—
Common mode input voltage	V_{CM}	—	$V_{xcorevss}$	—	V	6

Notes:
1. Input must be externally AC-coupled.
2. $V_{RX\_DIFFp\text{-}p}$ is also referred to as peak to peak input differential voltage
3. The concept of this parameter is equivalent to the Electrical Idle Detect Threshold parameter in PCI Express. See Table 72 for further explanation.
4. The LSTS shown in the table refers to the LSTSA or LSTSE bit field of chip's SerDes 2 control register.
5. $V_{CM\_ACp\text{-}p}$ is also referred to as peak to peak AC common mode voltage.
6. On-chip termination to S2GND (xcorevss).

2.9.3.4 SGMII AC Timing Specifications

This section describes the SGMII transmit and receive AC timing specifications. Transmitter and receiver characteristics are measured at the transmitter outputs (SD2_TX[n] and $\overline{\text{SD2\_TX}}$[n]) or at the receiver inputs (SD2_RX[n] and $\overline{\text{SD2\_RX}}$[n]) as depicted in Figure 32 respectively.

2.9.3.4.1 SGMII Transmit AC Timing Specifications

This table provides the SGMII transmit AC timing targets. A source synchronous clock is not provided.

Table 41. SGMII Transmit AC Timing Specifications

At recommended operating conditions with $X2V_{DD}$ = 1.0V ± 5%.

Parameter	Symbol	Min	Typ	Max	Unit	Notes
Deterministic Jitter	JD	—	—	0.17	UI p-p	—
Total Jitter	JT	—	—	0.35	UI p-p	—
Unit Interval	UI	799.92	800	800.08	ps	1
V_{OD} fall time (80%-20%)	tfall	50	—	120	ps	—
V_{OD} rise time (20%-80%)	t_{rise}	50	—	120	ps	—

Notes:
1. Each UI is 800 ps ± 100 ppm.

Table 53. Local Bus General Timing Parameters (BV_{DD} = 1.8 V DC) (continued)

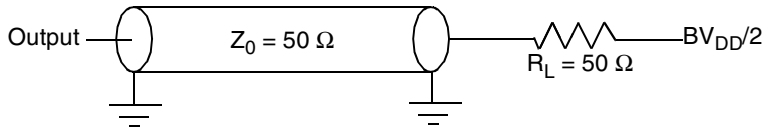
Parameter	Configuration	Symbol [1]	Min	Max	Unit	Notes
Output hold from local bus clock for LAD/LDP	—	$t_{LBKHOX2}$	0.9	—	ns	3
Local bus clock to output high Impedance (except LAD/LDP and LALE)	—	$t_{LBKHOZ1}$	—	2.6	ns	5
Local bus clock to output high impedance for LAD/LDP	—	$t_{LBKHOZ2}$	—	2.6	ns	5

Note:

1. The symbols used for timing specifications herein follow the pattern of $t_{\text{(First two letters of functional block)(signal)(state) (reference)(state)}}$ for inputs and $t_{\text{(First two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, $t_{LBIXKH1}$ symbolizes local bus timing (LB) for the input (I) to go invalid (X) with respect to the time the t_{LBK} clock reference (K) goes high (H), in this case for clock one(1). Also, t_{LBKHOX} symbolizes local bus timing (LB) for the t_{LBK} clock reference (K) to go high (H), with respect to the output (O) going invalid (X) or output hold time.
2. All timings are in reference to LSYNC_IN for PLL enabled and internal local bus clock for PLL bypass mode.
3. All signals are measured from $BV_{DD}/2$ of the rising edge of LSYNC_IN for PLL enabled or internal local bus clock for PLL bypass mode to $0.4 \times BV_{DD}$ of the signal in question for 1.8-V signaling levels.
4. Input timings are measured at the pin.
5. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
6. t_{LBOTOT} is a measurement of the minimum time between the negation of LALE and any change in LAD. t_{LBOTOT} is guaranteed with LBCR[AHD] = 0.
7. Maximum possible clock skew between a clock LCLK[m] and a relative clock LCLK[n]. Skew measured between complementary signals at $BV_{DD}/2$.

This figure provides the AC test load for the local bus.

Figure 38. Local Bus AC Test Load



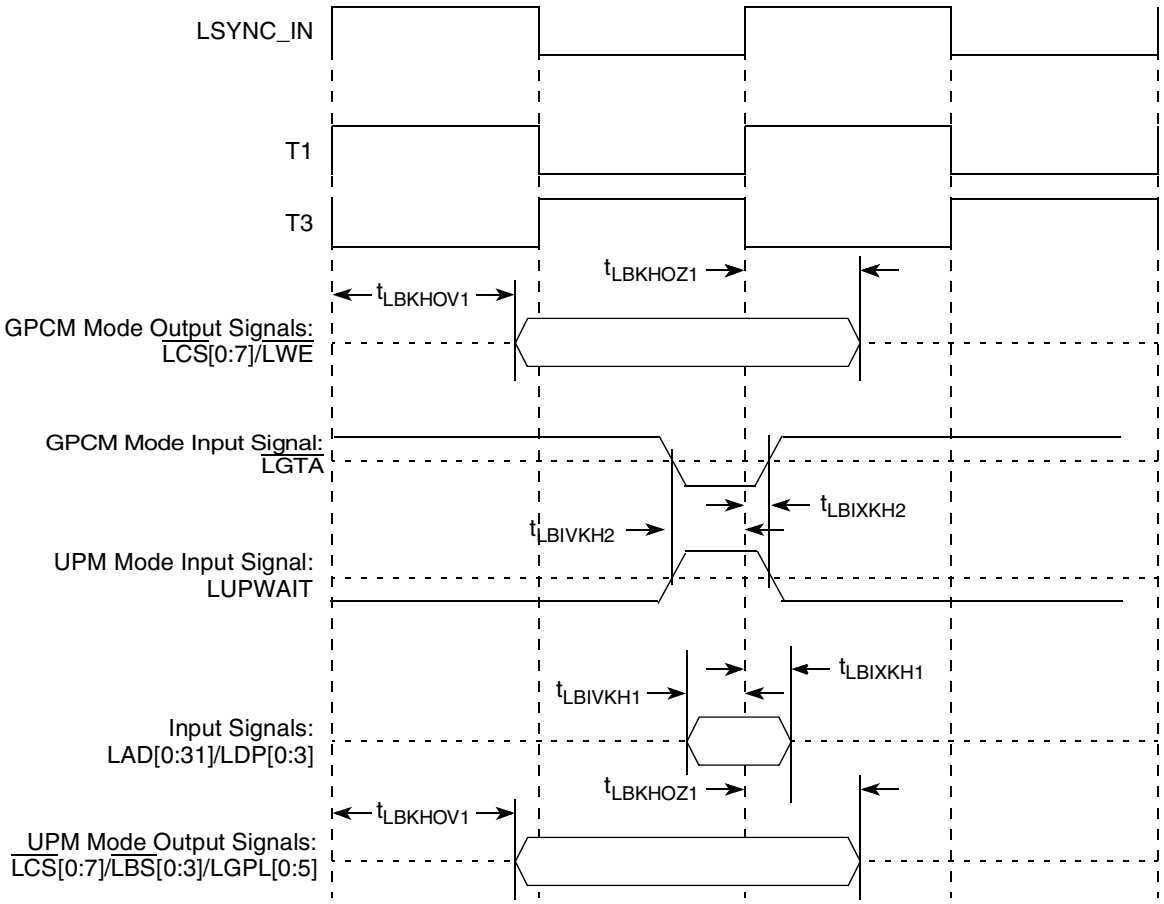


Figure 41. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 4(PLL Enabled)

2.16.1 Requirements for SATA REF_CLK

The AC requirements for the SATA reference clock are listed in the following table.

Table 59. Reference Clock Input Requirements

Parameter	Symbol	Min	Typical	Max	Unit	Notes
SD2_REF_CLK/_B reference clock cycle time	t_{CLK_REF}	100	—	150	MHz	1
SD2_REF_CLK/_B frequency tolerance	t_{CLK_TOL}	–350	0	+350	ppm	—
SD_REF_CLK/_B rise/fall time (80%-20%)	$t_{CLK\_RISE}/t_{CLK\_FALL}$	—	—	1	ns	—
SD_REF_CLK/_B duty cycle (@50% X2VDD)	t_{CLK_DUTY}	45	50	55	%	—
SD_REF_CLK/_B cycle to cycle clock jitter (period jitter)	t_{CLK_CJ}	—	—	100	ps	—
SD_REF_CLK/_B phase jitter (peak-to-peak)	t_{CLK_PJ}	–50	—	+50	ps	2,3

Note:

1. Only 100/125/150 MHz have been tested, other in between values will not work correctly with the rest of the system.
2. In a frequency band from 150 kHz to 15 MHz, at BER of 10E-12.
3. Total peak-to-peak deterministic jitter “Dj” should be less than or equal to 50 ps.

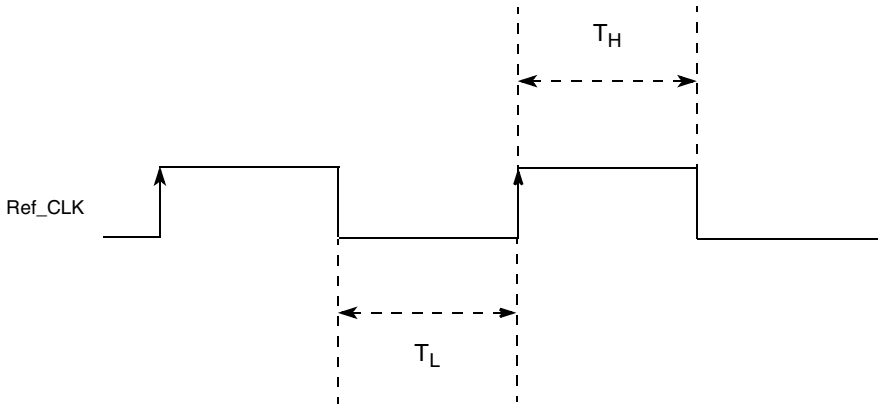


Figure 49. Reference Clock Timing Waveform

Table 79. Package Thermal Characteristics (continued)

Characteristic	JEDEC Board	Symbol	Value	Unit	Notes
Junction-to-ambient (@200 ft/min)	Four layer board (2s2p)	$R_{\theta JA}$	14	°C/W	1, 2
Junction-to-board thermal	—	$R_{\theta JB}$	10	°C/W	3
Junction-to-case thermal	—	$R_{\theta JC}$	< 0.1	°C/W	4

Notes

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
2. Per JEDEC JESD51-2 and JESD51-6 with the board (JESD51-9) horizontal.
3. Thermal resistance between the die and the printed-circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
4. Thermal resistance between the active surface of the die and the case top surface determined by the cold plate method (MIL SPEC-883 Method 1012.1) with the calculated case temperature. Actual thermal resistance is less than 0.1 •C/W

Simulations with heat sinks were done with the package mounted on the 2s2p thermal test board. The thermal interface material was a typical thermal grease such as Dow Corning 340 or Wakefield 120 grease.For system thermal modeling, the chip's thermal model without a lid is shown in Figure 72 The substrate is modeled as a block 29 x 29 x 1.2 mm with an in-plane conductivity of 19.8 W/m•K and a through-plane conductivity of 1.13 W/m•K. The solder balls and air are modeled as a single block 29 x 29 x 0.5 mm with an in-plane conductivity of 0.034 W/m•K and a through plane conductivity of 12.1 W/m•K. The die is modeled as 9.6 x 9.57 mm with a thickness of 0.75 mm. The bump/underfill layer is modeled as a collapsed thermal resistance between the die and substrate assuming a conductivity of 7.5 W/m•K in the thickness dimension of 0.07 mm. The die is centered on the substrate. The thermal model uses approximate dimensions to reduce grid. Please refer to the case outline for actual dimensions.

2.24.2 Recommended Thermal Model

This table shows the chip's thermal model.

Table 80. Thermal Model

Conductivity	Value	Units
Die (9.6x9.6 × 0.85 mm)		
Silicon	Temperature dependent	—
Bump/Underfill (9.6 x 9.6 × 0.07 mm) Collapsed Thermal Resistance		
Kz	7.5	W/m•K
Substrate (29 × 29 × 1.2 mm)		
Kx	19.8	W/m•K
Ky	19.8	
Kz	1.13	
Solder and Air (29 × 29 × 0.5 mm)		
Kx	0.034	W/m•K
Ky	0.034	
Kz	12.1	

Careful board layout with stubless connections to these pull-down resistors coupled with the large value of the pull-down resistor should minimize the disruption of signal quality or speed for output pins thus configured.

The platform PLL ratio and e500 PLL ratio configuration pins are not equipped with these default pull-up devices.

3.10 JTAG Configuration Signals

Correct operation of the JTAG interface requires configuration of a group of system control pins as demonstrated in Figure 78. Care must be taken to ensure that these pins are maintained at a valid deasserted state under normal operating conditions as most have asynchronous behavior and spurious assertion will give unpredicatable results.

Boundary-scan testing is enabled through the JTAG interface signals. The $\overline{\text{TRST}}$ signal is optional in the IEEE 1149.1 specification, but it is provided on all processors built on Power Architecture technology. The chip requires $\overline{\text{TRST}}$ to be asserted during power-on reset flow to ensure that the JTAG boundary logic does not interfere with normal chip operation. While the TAP controller can be forced to the reset state using only the TCK and TMS signals, generally systems assert $\overline{\text{TRST}}$ during the power-on reset flow. Simply tying $\overline{\text{TRST}}$ to $\overline{\text{HRESET}}$ is not practical because the JTAG interface is also used for accessing the common on-chip processor (COP), which implements the debug interface to the chip.

The COP function of these processors allow a remote computer system (typically, a PC with dedicated hardware and debugging software) to access and control the internal operations of the processor. The COP interface connects primarily through the JTAG port of the processor, with some additional status monitoring signals. The COP port requires the ability to independently assert $\overline{\text{HRESET}}$ or $\overline{\text{TRST}}$ in order to fully control the processor. If the target system has independent reset sources, such as voltage monitors, watchdog timers, power supply failures, or push-button switches, then the COP reset signals must be merged into these signals with logic.

The arrangement shown in Figure 78 allows the COP port to independently assert $\overline{\text{HRESET}}$ or $\overline{\text{TRST}}$, while ensuring that the target can drive $\overline{\text{HRESET}}$ as well.

The COP interface has a standard header, shown in Figure 79, for connection to the target system, and is based on the 0.025" square-post, 0.100" centered header assembly (often called a Berg header). The connector typically has pin 14 removed as a connector key.

The COP header adds many benefits such as breakpoints, watchpoints, register and memory examination/modification, and other standard debugger features. An inexpensive option can be to leave the COP header unpopulated until needed.

There is no standardized way to number the COP header; consequently, many different pin numbers have been observed from emulator vendors. Some are numbered top-to-bottom then left-to-right, while others use left-to-right then top-to-bottom, while still others number the pins counter clockwise from pin 1 (as with an IC). Regardless of the numbering, the signal placement recommended in Figure 79 is common to all known emulators.

3.10.1 Termination of Unused Signals

If the JTAG interface and COP header will not be used, Freescale recommends the following connections:

- $\overline{\text{TRST}}$ should be tied to $\overline{\text{HRESET}}$ through a 0 kΩ isolation resistor so that it is asserted when the system reset signal ($\overline{\text{HRESET}}$) is asserted, ensuring that the JTAG scan chain is initialized during the power-on reset flow. Freescale recommends that the COP header be designed into the system as shown in Figure 78. If this is not possible, the isolation resistor will allow future access to $\overline{\text{TRST}}$ in case a JTAG interface may need to be wired onto the system in future debug situations.
- No pull-up/pull-down is required for TDI, TMS, or TDO.

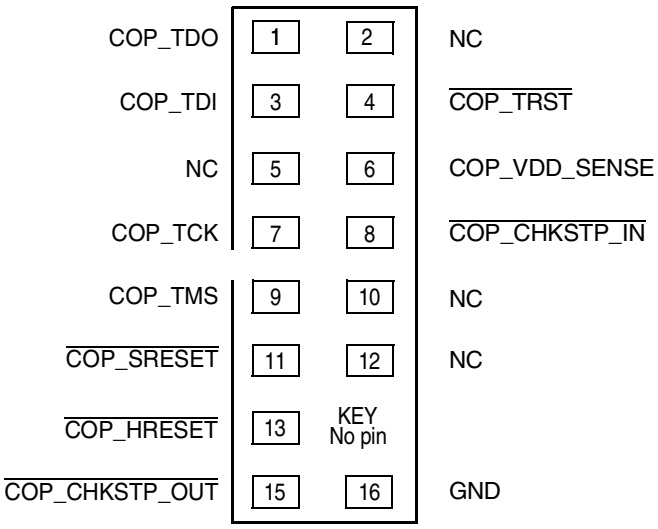


Figure 79. COP Connector Physical Pinout

3.11 Guidelines for High-Speed Interface Termination

3.11.1 SerDes1 Interface Entirely Unused

If the high-speed SerDes interface is not used at all, the unused pin should be terminated as described in this section. However, the SerDes must always have power applied to its supply pins. There are several reserved pins that need to be either left floating or connected to XGND. See SerDes1 in Table 1 for details.

The following pins must be left unconnected (float):

- SD1_TX[7:4]
- $\overline{\text{SD1\_TX[7:4]}}$
- Reserved pins T22, T23

The following pins must be connected to XGND:

- SD1_RX[7:4]
- $\overline{\text{SD1\_RX[7:4]}}$
- SD1_REF_CLK
- $\overline{\text{SD1\_REF\_CLK}}$

The POR configuration pin cfg_io_ports[0:2] on TSEC3_TXD[6:3] can be used to power down SerDes 1 block for power saving. Note that both SVDD and XVDD must remain powered.

3.11.2 SerDes 1 Interface Partly Unused

If only part of the high speed SerDes interface pins are used, the remaining high-speed serial I/O pins should be terminated as described in this section.

The following pins must be left unconnected (float) if not used:

- SD1_TX[7:4]
- $\overline{\text{SD1\_TX[7:4]}}$
- Reserved pins: T22, T23

5. Capacitors may not be present on all devices
6. Caution must be taken not to short exposed metal capacitor pads on package top.
7. All dimensions are symmetric across the package center lines, unless dimensioned otherwise.

6 Product Documentation

The following documents are required for a complete description of the chip and are needed to design properly with the part.

- *MPC8536E PowerQUICC III Integrated Processor Reference Manual* (document number: MPC8536ERM)
- *e500 PowerPC Core Reference Manual* (document number: E500CORERM)

7 Document Revision History

This table provides a revision history for this hardware specification.

Table 85. Document Revision History

Revision	Date	Substantive Change(s)
5	09/2011	• Removed PVDD from Table 1, “Pinout Listing.”
4	06/2011	• In Table 1, “Pinout Listing,” updated the power supply for TSEC3 pins to TVDD. • Updated Table 56, “eSDHC AC Timing Specifications.” • In Section 4.3, “Part Numbering,” added an extra bin (1250/500/667) to support DDR3.
3	11/2010	• In Table 1, “Pinout Listing,” added the following note: “For systems that boot from Local Bus (GPCM)-controlled NOR flash or (FCM) controlled NAND flash, a pullup on LGPL4 is required...” In addition, updated footnote 26 and added footnote 29 to PCI1_AD. • Updated Table 21 • Updated Figure 25, “RGMII and RTBI AC Timing and Multiplexing Diagrams.” • In Table 44, “MII Management DC Electrical Characteristics,” changed the Voh/Vol values for MDIO/MDC. • Added Note 6 regarding USB*n*_DIR pin to Table 47, “USB General Timing Parameters6.” • In Table 64, “I2C AC Electrical Specifications,” updated footnote 2. • In Table 82, , Table 83, , Table 84, added the Revision Level A for Rev 1.2
2	09/2009	**Note:** • In Section 1, “Pin Assignments and Reset States,”updated the first sentence of the note to say, “The UART_SOUT[0:1] and TEST_SEL pins must be set to a proper state during POR configuration.” • In Table 40, “SGMII DC Receiver Electrical Characteristics,” changed LSTSAB to LSTSA and LSTSEF to LSTSE for Note 4. • Updated Die value and Bump/Underfill value in Table 84 **Note:** Updated Figure 81, “Mechanical Dimensions and Bottom Surface Nomenclature of the FC-PBGA,” and its notes.
1	09/2009	• In Table 3, “Recommended Operating Conditions,” for V_{DD_CORE}, removed 1.1 ± 55 mV. • In Table 5, “Power Dissipation 5,” remove note 5. • In Table 5, ”Power Dissipation 5,” changed an “—” to “0.”
0	08/2009	• Initial public release.